

GBJ10A THRU GBJ10M

List

List..... 1

Package outline..... 2

Features..... 2

Mechanical data..... 2

Maximum ratings 2

Rating and characteristic curves..... 3

Pinning information..... 4

Marking..... 4

Tube packing..... 4

Suggested thermal profiles for soldering processes..... 5

High reliability test capabilities..... 6

GBJ10A THRU GBJ10M

10.0A Glass Passivated Single Phase Bridge Rectifiers - 50 - 1000V

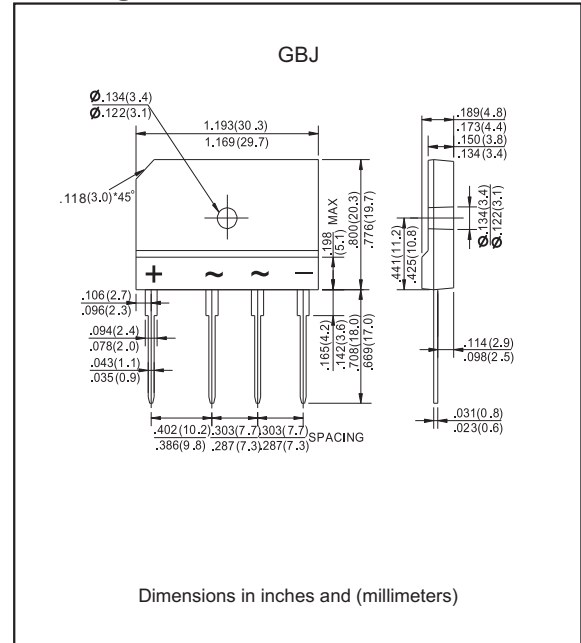
Features

- Rating to 1000V PRV
- Ideal for printed circuit board
- Low forward voltage drop, high current capability
- Reliable low cost construction utilizing molded plastic technique results in inexpensive product
- Glass passivated chip junction.
- Lead-free parts meet RoHS requirements.
- UL recognized file # E321971
- Suffix "-H" indicates Halogen free parts, ex. GBJ10A-H.

Mechanical data

- Epoxy: UL94-V0 rated flame retardant
- Case : Molded plastic, GBJ
- Terminals : Solder plated, solderable per MIL-STD-750, Method 2026
- Polarity : marked on body
- Mounting Position : Any
- Weight : Approximated 7.00 gram

Package outline



Maximum ratings and Electrical Characteristics (AT $T_A=25^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	CONDITIONS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Maximum average forward rectified current	with heatsink Note 1 @ $T_c=110^{\circ}\text{C}$ without heatsink	$I_{F(AV)}$			10.0 3.0	A
Forward surge current	8.3ms single half sine-wave (JEDEC methode)	I_{FSM}			220	A
Reverse current	$V_R = V_{RRM}$ $T_J = 25^{\circ}\text{C}$	I_R			10.0	μA
	$V_R = V_{RRM}$ $T_J = 125^{\circ}\text{C}$				500	
Rating for fusing	$t < 8.3$ ms	I^2t			200	A^2s
Typical Junction capacitance Per Element	Measured at 1.0MHz and applied reverse voltage of 4.0V DC	C_J		55		pF
Typical thermal resistance	Junction to case	$R_{\theta JC}$		1.4		$^{\circ}\text{C/W}$
Storage temperature		T_{STG}	-65		+175	$^{\circ}\text{C}$

Note: 1. Device mounted on 150mm*150mm*1.6mm Cu plate heatsink.

SYMBOLS	V_{RRM}^{*1} (V)	V_{RMS}^{*2} (V)	V_R^{*3} (V)	V_F^{*4} (V)	Operating temperature T_J , ($^{\circ}\text{C}$)
GBJ10A	50	35	50	1.10	-55 to +150
GBJ10B	100	70	100		
GBJ10D	200	140	200		
GBJ10G	400	280	400		
GBJ10J	600	420	600		
GBJ10K	800	560	800		
GBJ10M	1000	700	1000		

- *1 Repetitive peak reverse voltage
- *2 RMS voltage
- *3 Continuous reverse voltage
- *4 Maximum forward voltage@ $I_F=5.0\text{A}$

Rating and characteristic curves (GBJ10A THRU GBJ10M)

FIG.1-FORWARD CURRENT DERATING CURVE

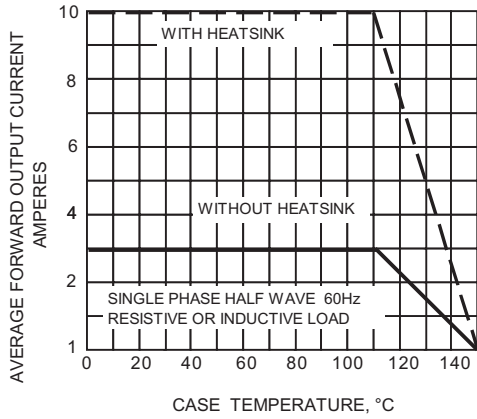


FIG.2-MAXMUN NON-REPETITIVE SURGE CURRENT

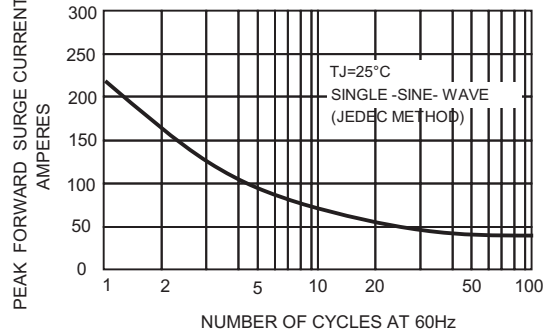


FIG.3-TYPICAL JUNCTION CAPACITANCE

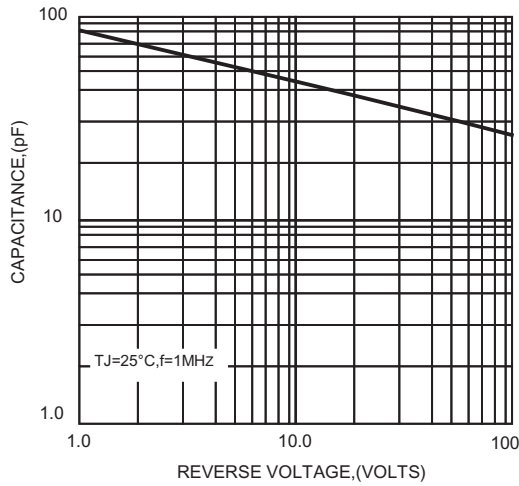


FIG.4-TYPICAL FORWARD CHARACTERISTICS

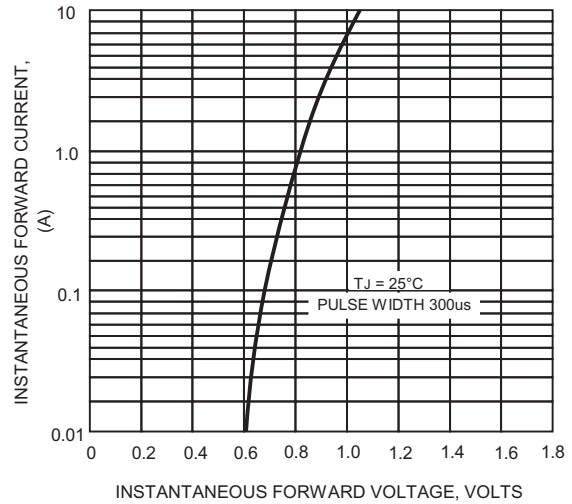
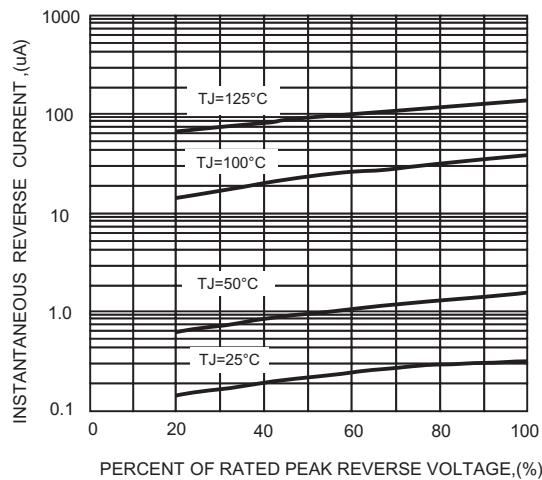
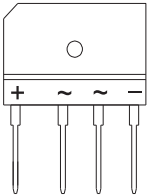
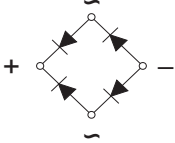


FIG.5-TYPICAL REVERSE CHARACTERISTICS



GBJ10A THRU GBJ10M

Pinning information

Simplified outline	Symbol
	

Marking

Type number	Marking code
GBJ10A	GBJ10A
GBJ10B	GBJ10B
GBJ10D	GBJ10D
GBJ10G	GBJ10G
GBJ10J	GBJ10J
GBJ10K	GBJ10K
GBJ10M	GBJ10M

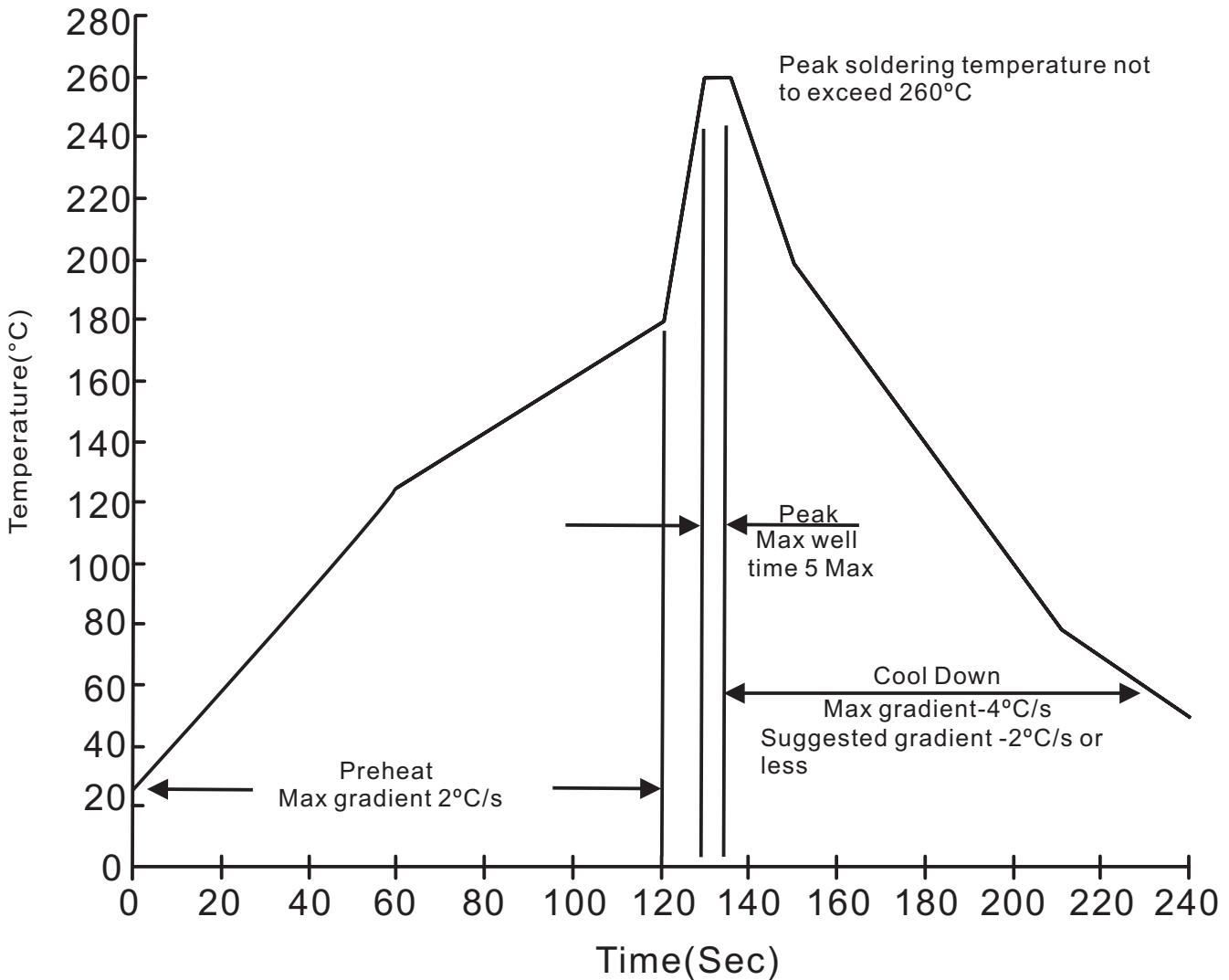
Tube packing

PACKAGE	TUBE (pcs)	TUBE SIZE (m/m)	CARTON SIZE (m/m)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
GBJ	20	475*42.0*8.1	496*224*101	2,000	20.8

GBJ10A THRU GBJ10M

Suggested thermal profiles for soldering processes

1. Lead free temperature profile wave-soldering



GBJ10A THRU GBJ10M

High reliability test capabilities

Item Test	Conditions	Reference
1. Solder Resistance	at 260±5°C for 10±2sec. immerse body into solder 1/16"±1/32"	MIL-STD-750D METHOD-2031
2. Solderability	at 245±5°C for 5 sec.	MIL-STD-202F METHOD-208
3. High Temperature Reverse Bias	$V_R=80\%$ rate at $T_J=150^\circ\text{C}$ for 168 hrs.	MIL-STD-750D METHOD-1038
4. Forward Operation Life	Rated average rectifier current at $T_A=25^\circ\text{C}$ for 500hrs.	MIL-STD-750D METHOD-1027
5. Intermittent Operation Life	$T_A = 25^\circ\text{C}$, $I_F = I_o$ On state: power on for 5 min. off state: power off for 5 min. on and off for 500 cycles.	MIL-STD-750D METHOD-1036
6. Pressure Cooker	$15P_{SIG}$ at $T_A=121^\circ\text{C}$ for 4 hrs.	JESD22-A102
7. Temperature Cycling	-55°C to +125°C dwelled for 30 min. and transferred for 5min. total 10 cycles.	MIL-STD-750D METHOD-1051
8. Forward Surge	8.3ms single half sine-wave , one surge.	MIL-STD-750D METHOD-4066-2
9. Humidity	at $T_A=85^\circ\text{C}$, RH=85% for 1000hrs.	MIL-STD-750D METHOD-1021
10. High Temperature Storage Life	at 175°C for 1000 hrs.	MIL-STD-750D METHOD-1031